

# 1.5A USB-FRIENDLY Li-Ion BATTERY CHARGER AND POWER-PATH MANAGEMENT IC

Check for Samples: bq24075-Q1

# **FEATURES**

- Qualified for Automotive Applications
- AEC-Q100 Qualified with the following results
  - Device Temperature Grade 1: -40°C to +125°C Ambient Operating Temperature Range
  - Device HBM ESD Classification Level H2
  - Device CDM ESD Classification Level C3B
- Fully Compliant USB Charger
  - Selectable 100mA and 500mA Maximum Input Current
  - 100mA Maximum Current Limit Ensures
     Compliance to USB-IF Standard
  - Input based Dynamic Power Management (V<sub>IN</sub>-DPM) for Protection Against Poor USB Sources
- 28V Input Rating with Overvoltage Protection
- Integrated Dynamic Power Path Management (DPPM) Function Simultaneously and Independently Powers the System and Charges the Battery
- Supports up to 1.5A Charge Current with Current Monitoring Output (ISET)
- Programmable Input Current Limit up to 1.5A for Wall Adapters
- Battery Disconnect Function with SYSOFF Input
- Programmable Pre-Charge and Fast-Charge Safety Timers
- Reverse Current, Short-Circuit and Thermal Protection
- NTC Thermistor Input
- Proprietary Start Up Sequence Limits Inrush Current
- Status Indication Charging/Done, Power Good
- Small 3 mm × 3 mm 16 Lead QFN Package

#### **APPLICATIONS**

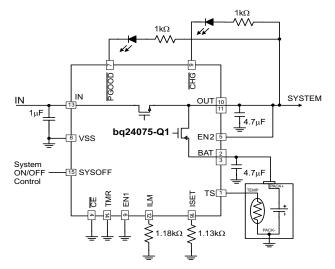
Automotive

### DESCRIPTION

The bq24075-Q1 device is integrated Li-ion linear charger and system power path management device targeted at space-limited portable applications. The device operate from either a USB port or AC adapter and support charge currents up to 1.5A. The input voltage range with input overvoltage protection supports unregulated adapters. The USB input current limit accuracy and start up sequence allow the bq24075-Q1 to meet USB-IF inrush current specification. Additionally, the input dynamic power management ( $V_{\rm IN}$ -DPM) prevents the charger from crashing incorrectly configured USB sources.

The bq24075-Q1 features dynamic power path management (DPPM) that powers the system while simultaneously and independently charging the battery. The DPPM circuit reduces the charge current when the input current limit causes the system output to fall to the DPPM threshold; thus, supplying the system load at all times while monitoring the charge current separately. This feature reduces the number of charge and discharge cycles on the battery, allows for proper charge termination and enables the system to run with a defective or absent battery pack.

# **Typical Application Circuit**





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# **DESCRIPTION (CONTINUED)**

Additionally, the regulated system input enables instant system turn-on when plugged in even with a totally discharged battery. The power-path management architecture also permits the battery to supplement the system current requirements when the adapter cannot deliver the peak system currents, enabling the use of a smaller adapter.

The battery is charged in three phases: conditioning, constant current, and constant voltage. In all charge phases, an internal control loop monitors the IC junction temperature and reduces the charge current if the internal temperature threshold is exceeded. The charger power stage and charge current sense functions are fully integrated. The charger function has high accuracy current and voltage regulation loops, charge status display, and charge termination. The input current limit and charge current are programmable using external resistors.

#### ORDERING INFORMATION

PART NUMBER	V <sub>OVP</sub>	V <sub>BAT(REG)</sub>	V <sub>OUT(REG)</sub>	V <sub>DPPM</sub>	OPTIONAL FUNCTION	MARKING
bq24075QRGTRQ1	6.6 V	4.2V	5.5 V	4.3 V	SYSOFF	SAM

- (1) The RGT package is available in the following options:
  - R taped and reeled in quantities of 3,000 devices per reel.
  - T taped and recled in quantities of 3,000 devices per reel.
- (2) This product is RoHS compatible, including a lead concentration that does not exceed 0.1% of total product weight, and is suitable for use in specified lead-free soldering processes. In addition, this product uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

# ABSOLUTE MAXIMUM RATINGS(1)

over the -40°C to 125°C operating free-air temperature range (unless otherwise noted)

			VA	LUE	UNIT
			MIN	MAX	
		IN (with respect to VSS)	-0.3	28	V
V <sub>I</sub>	Input Voltage	BAT (with respect to VSS)	-0.3	5	V
٧١	input voltage	OUT, EN1, EN2, $\overline{\text{CE}}$ , TS, ISET, $\overline{\text{PGOOD}}$ , $\overline{\text{CHG}}$ , ILIM, TMR, SYSOFF	-0.3	7	V
I <sub>I</sub>	Input Current	IN		1.6	Α
		OUT		5	А
$I_{O}$	Output Current (Continuous)	BAT (Discharge mode)		5	А
	(Continuous)	BAT (Charging mode)		1.5 <sup>(2)</sup>	А
	Output Sink Current	CHG, PGOOD		15	mA
Electros	tatic Discharge (HBM) Q	SS 009-105 (JESD22-A114A) <sup>(3)</sup>		1.5	kV
TJ	Junction temperature		-40	150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C
ESD	Human Body Model (HBM) AEC-Q100 Classification Level H2			2	kV
Rating	Charged Device Mod	Charged Device Model (CDM) AEC-Q100 Classification Level C3B			V

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. All voltage values are with respect to the network ground terminal unless otherwise noted.
- (2) The IC operational charging life is reduced to 20,000 hours, when charging at 1.5A and 125°C. The thermal regulation feature reduces charge current if the IC's junction temperature reaches 125°C; thus without a good thermal design the maximum programmed charge current may not be reached.
- (3) The human body model is a 100-pF capacitor discharged through a 1.5-kΩ resistor into each pin.

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## THERMAL INFORMATION

	THERMAL METRIC <sup>(1)</sup>	BQ24075-Q1	LINUTO
	THERMAL METRIC	RGT 16-PINS	UNITS
$\theta_{JA}$	Junction-to-ambient thermal resistance	45.8	
$\theta_{JCtop}$	Junction-to-case (top) thermal resistance	53.6	
$\theta_{JB}$	Junction-to-board thermal resistance	18.1	°C/\\/
ΨЈТ	Junction-to-top characterization parameter	1.1	°C/W
ΨЈВ	Junction-to-board characterization parameter	18.0	
$\theta_{JCbot}$	Junction-to-case (bottom) thermal resistance	5.2	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

# RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V	IN voltage range	4.35	26	V
VI	IN operating voltage range	4.35	6.4	V
I <sub>IN</sub>	Input current, IN pin		1.5	Α
I <sub>OUT</sub>	Current, OUT pin		4.5	Α
I <sub>BAT</sub>	Current, BAT pin (Discharging)		4.5	Α
I <sub>CHG</sub>	Current, BAT pin (Charging)		1.5 <sup>(1)</sup>	Α
R <sub>ILIM</sub>	Maximum input current programming resistor	1100	8000	Ω
R <sub>ISET</sub>	Fast-charge current programming resistor (2)	590	3000	Ω
R <sub>ITERM</sub>	Termination current programming resistor	0	15	kΩ
R <sub>TMR</sub>	Timer programming resistor	18	72	kΩ

<sup>(1)</sup> The IC operational charging life is reduced to 20,000 hours, when charging at 1.5A and 125°C. The thermal regulation feature reduces charge current if the IC's junction temperature reaches 125°C; thus without a good thermal design the maximum programmed charge current may not be reached.

<sup>(2)</sup> Use a 1% tolerance resistor for R<sub>ISET</sub> to avoid issues with the R<sub>ISET</sub> short test when using the maximum charge current setting.



# **ELECTRICAL CHARACTERISTICS**

Over ambient temperature range (-40C $^{\circ} \le T_A \le 125$  $^{\circ}$ C) and the recommended supply voltage range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT						
UVLO	Undervoltage lock-out	$V_{IN}$ : 0 V $\rightarrow$ 4 V	3.2	3.3	3.4	V
V <sub>hys</sub>	Hysteresis on UVLO	$V_{IN}$ : 4 V $\rightarrow$ 0 V	200		300	mV
V <sub>IN(DT)</sub>	Input power detection threshold	Input power detected when $V_{IN} > V_{BAT} + V_{IN(DT)}$ $V_{BAT} = 3.6 \text{ V}, \text{ VIN: } 3.5 \text{ V} \rightarrow 4 \text{ V}$	50	80	135	mV
V <sub>hys</sub>	Hysteresis on V <sub>IN(DT)</sub>	$V_{BAT} = 3.6 \text{ V}, V_{IN}: 4 \text{ V} \rightarrow 3.5 \text{ V}$	20			mV
t <sub>DGL(PGOOD)</sub>	Deglitch time, input power detected status	Time measured from V <sub>IN</sub> : 0 V $\rightarrow$ 5 V 1 $\mu s$ rise-time to $\overline{PGOOD}$ = LO		1.2		ms
V <sub>OVP</sub>	Input overvoltage protection threshold	$V_{IN}$ : 5 V $\rightarrow$ 7 V	6.4	6.6	6.8	V
V <sub>hys</sub>	Hysteresis on OVP	$V_{IN}$ : 7 V $\rightarrow$ 5V		110		mV
t <sub>DGL(OVP)</sub>	Input overvoltage blanking time (OVP fault deglitch)			50		μs
t <sub>REC</sub>	Input overvoltage recovery time	Time measured from V <sub>IN</sub> : 11 V $\rightarrow$ 5 V with 1 $\mu$ s fall-time to $\overrightarrow{PGOOD}$ = LO		1.2		ms
ILIM, ISET SI	HORT CIRCUIT DETECTION (CHECKED DURING STA	ARTUP)	-			
I <sub>sc</sub>	Current source	$V_{IN}$ > UVLO and $V_{IN}$ > $V_{BAT}$ + $V_{IN(DT)}$		1.3		mA
V <sub>SC</sub>		$V_{IN}$ > UVLO and $V_{IN}$ > $V_{BAT}$ + $V_{IN(DT)}$		520		mV
QUIESCENT	CURRENT	,	II.			
I <sub>BAT(PDWN)</sub>	Sleep current into BAT pin	$\overline{\text{CE}}$ = LO or HI, input power not detected, No load on OUT pin, T <sub>a</sub> = 125°C			12	μΑ
I <sub>IN</sub> St	0	EN1= HI, EN2=HI, V <sub>IN</sub> = 6 V, T <sub>a</sub> = 125°C			65	
	Standby current into IN pin	EN1= HI, EN2=HI, V <sub>IN</sub> = 10 V, T <sub>a</sub> = 125°C			200	μΑ
I <sub>cc</sub>	Active supply current, IN pin	$\overline{\text{CE}}$ = LO, V <sub>IN</sub> = 6 V, no load on OUT pin, V <sub>BAT</sub> > V <sub>BAT(REG)</sub> , (EN1, EN2) $\neq$ (HI, HI)			1.5	mA
POWER PAT	тн					=======================================
V <sub>DO(IN-OUT)</sub>	$V_{IN} - V_{OUT}$	V <sub>IN</sub> = 4.3 V, I <sub>IN</sub> = 1A, V <sub>BAT</sub> = 4.2V		300	475	mV
V <sub>DO(BAT-OUT)</sub>	V <sub>BAT</sub> – V <sub>OUT</sub>	I <sub>OUT</sub> = 1 A, V <sub>IN</sub> = 0 V, V <sub>BAT</sub> > 3 V		50	100	mV
V <sub>O(REG)</sub>	OUT pin voltage regulation	$V_{IN} > V_{OUT} + V_{DO(IN-OUT)}$	5.4	5.5	5.65	V
-()		EN1 = LO, EN2 = LO	85	95	100	
I <sub>IN</sub> max	Maximum input current	EN1 = HI, EN2 = LO	440	475	500	mA
		EN2 = HI, EN1 = LO		K <sub>ILIM</sub> /R <sub>ILIM</sub>		Α
		I <sub>LIM</sub> = 500mA to 1.5A	1500	1610	1720	
K <sub>ILIM</sub>	Maximum input current factor	I <sub>LIM</sub> = 200mA to 500mA	1300	1525	1770	ΑΩ
I <sub>IN</sub> max	Programmable input current limit range	EN2 = HI, EN1 = LO, $R_{ILIM}$ = 8 kΩ to 1.1 kΩ	200		1500	mA
V <sub>IN-DPM</sub>	Input voltage threshold when input current is reduced	EN2 = LO, EN1 = X	4.35	4.5	4.63	V
$V_{DPPM}$	Output voltage threshold when charging current is reduced		4.2	4.3	4.4	V
V <sub>BSUP1</sub>	Enter battery supplement mode	$V_{BAT} = 3.6V, R_{ILIM} = 1.5k\Omega, R_{LOAD} = 10\Omega \rightarrow 2\Omega$		V <sub>OUT</sub> ≤ V <sub>BAT</sub> -40mV		V
V <sub>BSUP2</sub>	Exit battery supplement mode	$V_{BAT} = 3.6V, R_{ILIM} = 1.5k\Omega, R_{LOAD} = 2\Omega \rightarrow 10\Omega$		V <sub>OUT</sub> ≥ V <sub>BAT</sub> –20mV		V
V <sub>O(SC1)</sub>	Output short-circuit detection threshold, power-on	$V_{\text{IN}} > V_{\text{UVLO}}$ and $V_{\text{IN}} > V_{\text{BAT}} + V_{\text{IN(DT)}}$	0.8	0.9	1	٧
V <sub>O(SC2)</sub>	Output short-circuit detection threshold, supplement mode $V_{BAT} - V_{OUT} > V_{O(SC2)}$ indicates short-circuit	$V_{IN} > V_{UVLO}$ and $V_{IN} > V_{BAT} + V_{IN(DT)}$	200	250	300	mV
t <sub>DGL(SC2)</sub>	Deglitch time, supplement mode short circuit			250		μs
t <sub>REC(SC2)</sub>	Recovery time, supplement mode short circuit			60		ms



# **ELECTRICAL CHARACTERISTICS (continued)**

Over ambient temperature range (-40C $^{\circ} \le T_A \le 125$  $^{\circ}$ C) and the recommended supply voltage range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
BATTERY C	HARGER					
ВАТ	Source current for BAT pin short-circuit detection	V <sub>BAT</sub> = 1.5V	4	7.5	11	mA
V <sub>BAT(SC)</sub>	BAT pin short-circuit detection threshold	V <sub>BAT</sub> rising	1.6	1.8	2	V
V <sub>BAT(REG)</sub>	Battery charge voltage		4.15	4.20	4.23	V
V <sub>LOWV</sub>	Pre-charge to fast-charge transition threshold	$V_{IN} > V_{UVLO}$ and $V_{IN} > V_{BAT} + V_{IN(DT)}$	2.9	3	3.1	V
t <sub>DGL1(LOWV)</sub>	Deglitch time on pre-charge to fast-charge transition			25		ms
t <sub>DGL2(LOWV)</sub>	Deglitch time on fast-charge to pre-charge transition			25		ms
	Battery fast charge current range	$V_{BAT(REG)} > V_{BAT} > V_{LOWV}, V_{IN} = 5 \text{ V } \overline{CE} = LO,$ EN1 = LO, EN2 = HI	300		1500	mA
I <sub>CHG</sub>	Battery fast charge current	$\label{eq:center}                                    $		K <sub>ISET</sub> /R <sub>ISET</sub>		Α
K <sub>ISET</sub>	Fast charge current factor		797	890	975	ΑΩ
I <sub>PRECHG</sub>	Pre-charge current			K <sub>PRECHG</sub> /R <sub>ISET</sub>	_	Α
K <sub>PRECHG</sub>	Pre-charge current factor		55	88	110	ΑΩ
I <sub>TERM</sub>	Termination comparator detection threshold	$\label{eq:continuous} \begin{array}{ c c } \hline CE = LO, \ (EN1, EN2) \neq (LO, LO), \\ V_{BAT} > V_{RCH}, \ t < t_{MAXCH}, \ V_{IN} = 5 \ V, \ DPPM \ loop \ and \ thermal \ loop \ not \ active \\ \end{array}$	0.09×I <sub>CHG</sub>	0.1×I <sub>CHG</sub>	0.11×I <sub>CHG</sub>	A
TERM	(internally set)	$\label{eq:continuous} \begin{array}{ c c c c }\hline CE = LO, \ (EN1, EN2) = (LO, LO),\\ V_{BAT} > V_{RCH}, \ t < t_{MAXCH}, \ V_{IN} = 5 \ V, \ DPPM \ loop \ and \ thermal \ loop \ not \ active \end{array}$	0.027×I <sub>CHG</sub>	0.033×I <sub>CHG</sub>	0.040×I <sub>CHG</sub>	Α
t <sub>DGL(TERM)</sub>	Deglitch time, termination detected			25		ms
$V_{RCH}$	Recharge detection threshold	$V_{IN} > V_{UVLO}$ and $V_{IN} > V_{BAT} + V_{IN(DT)}$	V <sub>BAT(REG)</sub> -140mV	V <sub>BAT(REG)</sub> -100mV	V <sub>BAT(REG)</sub> –55mV	V
t <sub>DGL(RCH)</sub>	Deglitch time, recharge threshold detected			62.5		ms
t <sub>DGL(NO-IN)</sub>	Delay time, input power loss to OUT LDO turn-off	$V_{BAT} = 3.6 \text{ V. Time measured from}$ $V_{\text{IN}} : 5 \text{ V} \rightarrow 3 \text{ V 1}$ µs fall-time		20		ms
I <sub>BAT(DET)</sub>	Sink current for battery detection	V <sub>BAT</sub> = 2.5V	5	7.5	10	mA
t <sub>DET</sub>	Battery detection timer	BAT high or low		250		ms
BATTERY C	HARGING TIMERS					
t <sub>PRECHG</sub>	Pre-charge safety timer value	TMR = floating	1440	1800	2160	s
t <sub>MAXCHG</sub>	Charge safety timer value	TMR = floating	14400	18000	21600	s
t <sub>PRECHG</sub>	Pre-charge safety timer value	18 kΩ < $R_{TMR}$ < 72 kΩ		R <sub>TMR</sub> × K <sub>TMR</sub>		s
t <sub>MAXCHG</sub>	Charge safety timer value	18 kΩ < $R_{TMR}$ < 72 kΩ		10×R <sub>TMR</sub> ×K <sub>TMF</sub>	t	s
K <sub>TMR</sub>	Timer factor		36	48	60	s/kΩ
BATTERY-PA	ACK NTC MONITOR <sup>(1)</sup>		"			
I <sub>NTC</sub>	NTC bias current	$V_{IN}$ > UVLO and $V_{IN}$ > $V_{BAT}$ + $V_{IN(DT)}$	72	75	80	μΑ
V <sub>HOT</sub>	High temperature trip point	Battery charging, V <sub>TS</sub> Falling	270	300	330	mV
V <sub>HYS(HOT)</sub>	Hysteresis on high trip point	Battery charging, V <sub>TS</sub> Rising from V <sub>HOT</sub>		30		mV
V <sub>COLD</sub>	Low temperature trip point	Battery charging, V <sub>TS</sub> Rising	2000	2100	2200	mV
V <sub>HYS(COLD)</sub>	Hysteresis on low trip point	Battery charging, V <sub>TS</sub> Falling from V <sub>COLD</sub>		300		mV
t <sub>DGL(TS)</sub>	Deglitch time, pack temperature fault detection	TS fault detected to charger disable		50		ms
	EGULATION		•		<u> </u>	
T <sub>J(REG)</sub>	Temperature regulation limit			125		°C
T <sub>J(OFF)</sub>	Thermal shutdown temperature	T <sub>J</sub> Rising		155		°C
T <sub>J(OFF-HYS)</sub>	Thermal shutdown hysteresis			20		°C

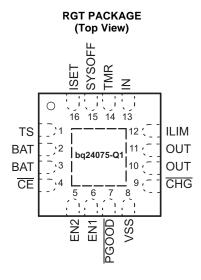
<sup>(1)</sup> These numbers set trip points of 0°C and 50°C while charging, with 3°C hysteresis on the trip points, with a Vishay Type 2 curve NTC with an R25 of 10 kΩ.



# **ELECTRICAL CHARACTERISTICS (continued)**

Over ambient temperature range (-40C°  $\le T_A \le 125$ °C) and the recommended supply voltage range (unless otherwise noted)

		· A · = / - · · · · · · · · · · · · · · · ·		(	,	
	PARAMETER	TEST CONDITION	NS MIN	TYP MAX	UNIT	
LOGIC LI	EVELS ON EN1, EN2, CE, SYSOFF		•			
V <sub>IL</sub>	Logic LOW input voltage		0	0.4	V	
V <sub>IH</sub>	Logic HIGH input voltage		1.4	6	V	
I <sub>IL</sub>	Input sink current	V <sub>IL</sub> = 0V		1	μA	
I <sub>IH</sub>	Input source current	V <sub>IH</sub> = 1.4V		10	μA	
LOGIC LI	LOGIC LEVELS ON PGOOD, CHG					
V <sub>OL</sub>	Output LOW voltage	I <sub>SINK</sub> = 5 mA		0.4	V	



# **PIN FUNCTIONS**

	PIN	1/0	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
TS	1	1	External NTC Thermistor Input. Connect the TS input to the NTC thermistor in the battery pack. TS monitors a $10k\Omega$ NTC thermistor. For applications that do not utilize the TS function, connect a $10k\Omega$ fixed resistor from TS to VSS to maintain a valid voltage level on TS.
BAT	2, 3	I/O	Charger Power Stage Output and Battery Voltage Sense Input. Connect BAT to the positive terminal of the battery. Bypass BAT to VSS with a 4.7 $\mu$ F to 47 $\mu$ F ceramic capacitor.
CE	4	I	Charge Enable Active-Low Input. Connect $\overline{\text{CE}}$ to a high logic level to place the battery charger in standby mode. In standby mode, OUT is active and battery supplement mode is still available. Connect $\overline{\text{CE}}$ to a low logic level to enable the battery charger. $\overline{\text{CE}}$ is internally pulled down with ~285 k $\Omega$ . Do not leave $\overline{\text{CE}}$ unconnected to ensure proper operation.
EN2	5	I	Input Current Limit Configuration Inputs. Use EN1 and EN2 control the maximum input current and
EN1	6	1	enable USB compliance. See Table 2 for the description of the operation states. EN1 and EN2 are internally pulled down with ≉285 kΩ. Do not leave EN1 or EN2 unconnected to ensure proper operation.
PGOOD	7	0	Open-drain Power Good Status Indication Output. PGOOD pulls to VSS when a valid input source is detected. PGOOD is high-impedance when the input power is not within specified limits. Connect PGOOD to the desired logic voltage rail using a 1kΩ-100kΩ resistor, or use with an LED for visual indication.
VSS	8	-	Ground. Connect to the thermal pad and to the ground rail of the circuit.
CHG	9	0	Open-Drain Charging Status Indication Output. $\overline{\text{CHG}}$ pulls to VSS when the battery is charging. $\overline{\text{CHG}}$ is high impedance when charging is complete and when charger is disabled. Connect $\overline{\text{CHG}}$ to the desired logic voltage rail using a $1 \text{k} \Omega$ - $100 \text{k} \Omega$ resistor, or use with an LED for visual indication.
OUT	10, 11	0	System Supply Output. OUT provides a regulated output when the input is below the OVP threshold and above the regulation voltage. When the input is out of the operation range, OUT is connected to $V_{BAT}$ except when SYSOFF is high. Connect OUT to the system load. Bypass OUT to VSS with a 4.7 $\mu$ F to 47 $\mu$ F ceramic capacitor.
ILIM	12	I	Adjustable Current Limit Programming Input. Connect a 1100 $\Omega$ to 8 k $\Omega$ resistor from ILIM to VSS to program the maximum input current (EN2=1, EN1=0). The input current includes the system load and the battery charge current. Leaving ILIM unconnected disables all charging.



# **PIN FUNCTIONS (continued)**

	PIN		DECORPORA
NAME	NO.	1/0	DESCRIPTION
IN	13	I	Input Power Connection. Connect IN to the external DC supply (AC adapter or USB port). The input operating range is 4.35V to 6.6V . The input can accept voltages up to 26V without damage but operation is suspended. Connect bypass capacitor 1 $\mu$ F to 10 $\mu$ F to VSS.
TMR	14	I	Timer Programming Input. TMR controls the pre-charge and fast-charge safety timers. Connect TMR to VSS to disable all safety timers. Connect a 18 k $\Omega$ to 72 k $\Omega$ resistor between TMR and VSS to program the timers a desired length. Leave TMR unconnected to set the timers to the default values.
SYSOFF	15	I	System Enable Input. Connect SYSOFF high to turn off the FET connecting the battery to the system output. When an adapter is connected, charging is also disabled. Connect SYSOFF low for normal operation. SYSOFF is internally pulled up to $V_{BAT}$ through a large resistor (~5 M $\Omega$ ). Do not leave SYSOFF unconnected to ensure proper operation.
ISET	16	I/O	Fast Charge Current Programming Input. Connect a 590 $\Omega$ to 3 k $\Omega$ resistor from ISET to VSS to program the fast charge current level. Charging is disabled if ISET is left unconnected. While charging, the voltage at ISET reflects the actual charging current and can be used to monitor charge current. See the CHARGE CURRENT TRANSLATOR section for more details.
Thermal Pad		-	There is an internal electrical connection between the exposed thermal pad and the VSS pin of the device. The thermal pad must be connected to the same potential as the VSS pin on the printed circuit board. Do not use the thermal pad as the primary ground input for the device. VSS pin must be connected to ground at all times.

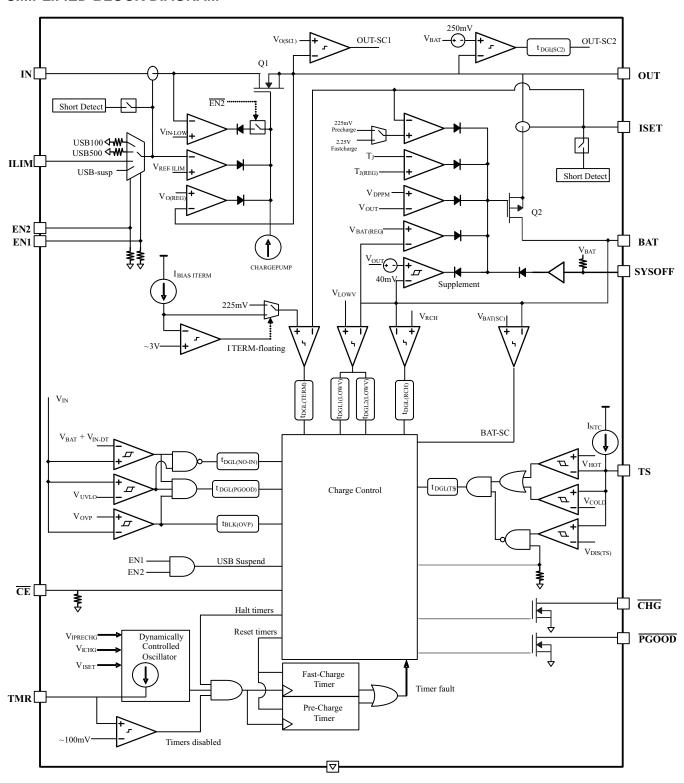
# Table 1. EN1/EN2 Settings

EN2	EN1	Maximum input current into IN pin
0	0	100 mA. USB100 mode
0	1	500 mA. USB500 mode
1	0	Set by an external resistor from ILIM to VSS
1	1	Standby (USB suspend mode)

Product Folder Link(s): bq24075-Q1



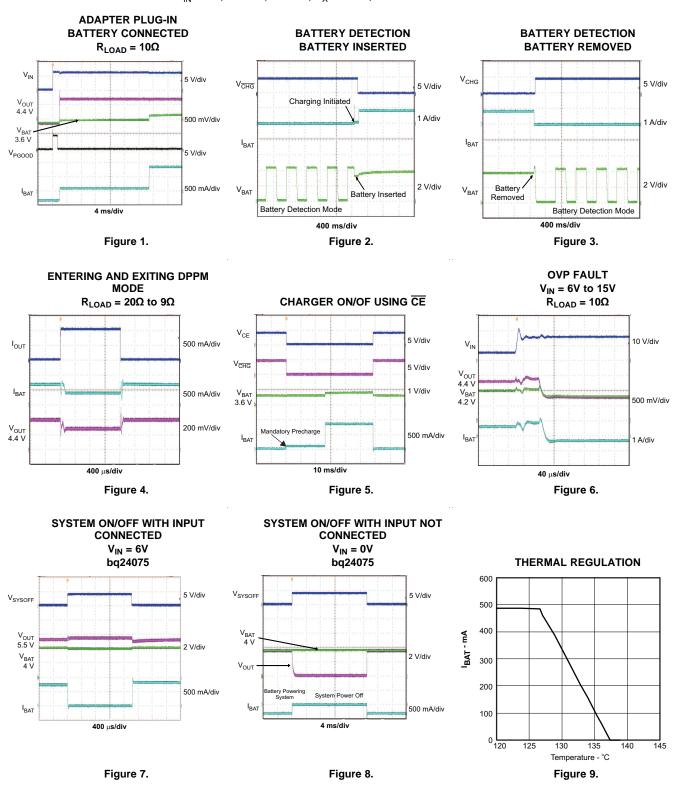
# SIMPLIFIED BLOCK DIAGRAM





# TYPICAL CHARACTERISTICS

 $V_{IN}$  = 6V, EN1=1, EN2=0,  $T_A$  = 25°C, unless otherwise noted.





# **TYPICAL CHARACTERISTICS (continued)**

 $V_{IN}$  = 6V, EN1=1, EN2=0,  $T_A$  = 25°C, unless otherwise noted.

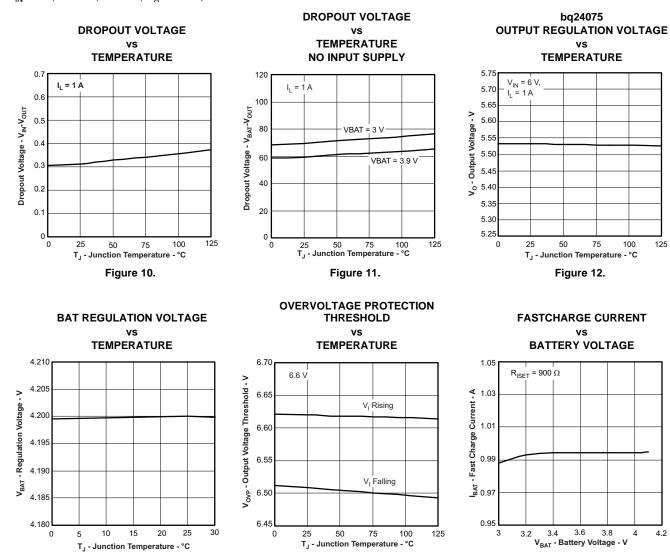


Figure 14. Figure 15.

 $\mathbf{T}_{\mathbf{J}}$  - Junction Temperature - °C Figure 13.

T<sub>.1</sub> - Junction Temperature - °C



# **TYPICAL CHARACTERISTICS (continued)**

 $V_{IN}$  = 6V, EN1=1, EN2=0,  $T_A$  = 25°C, unless otherwise noted.

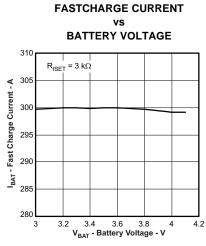


Figure 16.

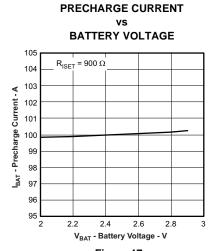


Figure 17.

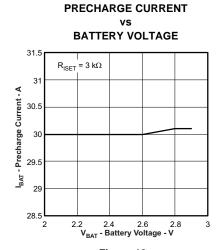


Figure 18.

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# **APPLICATION CIRCUITS**

 $V_{IN}$  = UVLO to  $V_{OVP}$ ,  $I_{FASTCHG}$  = 800mA,  $I_{IN(MAX)}$  = 1.3A, Battery Temperature Charge Range = 0°C to 50°C, 6.25 hour Fastcharge Safety Timer

 $V_{IN}$  = UVLO to  $V_{OVP}$ ,  $I_{FASTCHG}$  = 800mA,  $I_{IN(MAX)}$  = 1.3A,  $I_{TERM}$  = 110mA, Battery Temperature Charge Range = 0°C to 50°C, Safety Timers disabled

 $V_{IN}$  = UVLO to  $V_{OVP}$ ,  $I_{FASTCHG}$  = 800mA,  $I_{IN(MAX)}$  = 1.3A, Battery Temperature Charge Range = 0°C to 50°C, 6.25 hour Fastcharge Safety Timer

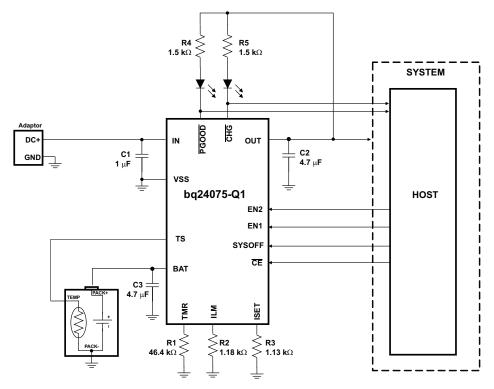


Figure 19. Using bg24075 to Disconnect the Battery from the System



# **EXPLANATION OF DEGLITCH TIMES AND COMPARATOR HYSTERESIS**

Figures not to scale

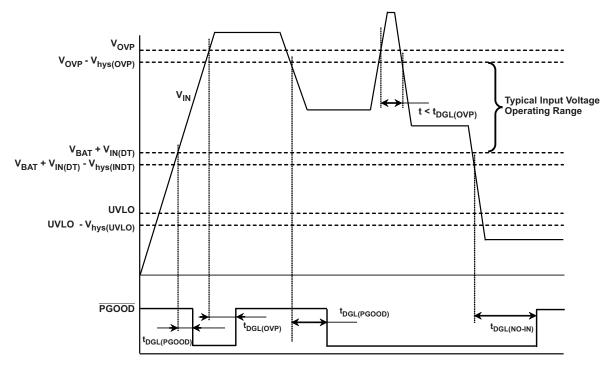


Figure 20. Power-Up, Power-Down, Power Good Indication

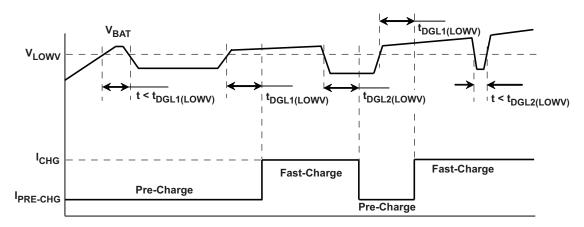


Figure 21. Pre- to Fast-Charge, Fast- to Pre-Charge Transition -  $t_{DGL1(LOWV)}$ ,  $t_{DGL2(LOWV)}$ 

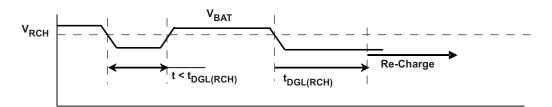


Figure 22. Recharge - t<sub>DGL(RCH)</sub>



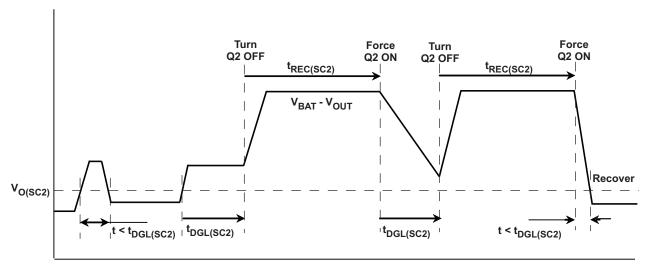


Figure 23. OUT Short-Circuit - Supplement Mode

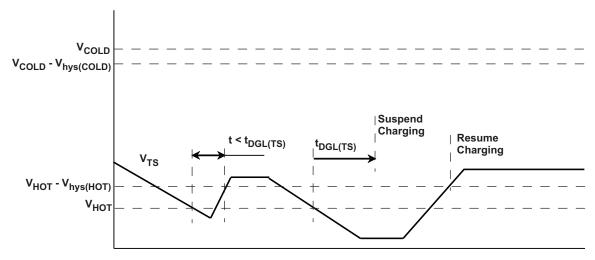


Figure 24. Battery Pack Temperature Sensing - TS Pin. Battery Temperature Increasing



#### DETAILED FUNCTIONAL DESCRIPTION

The bq24075-Q1 device is integrated Li-lon linear charger and system power path management device targeted at space-limited portable applications. The device powers the system while simultaneously and independently charging the battery. This feature reduces the number of charge and discharge cycles on the battery, allows for proper charge termination and enables the system to run with a defective or absent battery pack. It also allows instant system turn-on even with a totally discharged battery. The input power source for charging the battery and running the system can be an AC adapter or a USB port. The device features Dynamic Power Path Management (DPPM), which shares the source current between the system and battery charging, and automatically reduces the charging current if the system load increases. When charging from a USB port, the input dynamic power management ( $V_{\rm IN}$ -DPM) circuit reduces the input current if the input voltage falls below a threshold, preventing the USB port from crashing. The power-path architecture also permits the battery to supplement the system current requirements when the adapter cannot deliver the peak system currents.

### **UNDERVOLTAGE LOCKOUT (UVLO)**

The bq24075-Q1 family remains in power down mode when the input voltage at the IN pin is below the undervoltage threshold (UVLO).

During the power down mode the host commands at the control inputs ( $\underline{CE}$ ,  $\underline{EN1}$  and  $\underline{EN2}$ ) are ignored. The Q1 FET connected between IN and OUT pins is off, and the status outputs  $\underline{CHG}$  and  $\underline{PGOOD}$  are high impedance. The Q2 FET that connects BAT to OUT is ON. (If SYSOFF is high, Q2 is off). During power down mode, the  $V_{OUT(SC2)}$  circuitry is active and monitors for overload conditions on OUT.

#### **POWER ON**

When  $V_{IN}$  exceeds the UVLO threshold, the bq24075-Q1 powers up. While  $V_{IN}$  is below  $V_{BAT} + V_{IN(DT)}$ , the host commands at the control inputs ( $\overline{CE}$ ,  $\overline{EN}1$  and  $\overline{EN}2$ ) are ignored. The Q1 FET connected between IN and OUT pins is off, and the status outputs  $\overline{CHG}$  and  $\overline{PGOOD}$  are high impedance. The Q2 FET that connects BAT to OUT is ON. (If SYSOFF is high, Q2 is off). During this mode, the  $V_{OUT(SC2)}$  circuitry is active and monitors for overload conditions on OUT.

Once  $V_{IN}$  rises above  $V_{BAT} + V_{IN(DT)}$ ,  $\overline{PGOOD}$  is driven low to indicate the valid power status and the  $\overline{CE}$ , EN1, and EN2 inputs are read. The device enters standby mode if (EN1 = EN2 = HI) or if an input overvoltage condition occurs. In standby mode, Q1 is OFF and Q2 is ON so OUT is connected to the battery input. (If SYSOFF is high, FET Q2 is off). During this mode, the  $V_{OUT(SC2)}$  circuitry is active and monitors for overload conditions on OUT.

When the input voltage at IN is within the valid range:  $V_{IN} > UVLO$  **AND**  $V_{IN} > V_{BAT} + V_{IN(DT)}$  **AND**  $V_{IN} < V_{OVP}$ , and the EN1 and EN2 pins indicate that the USB suspend mode is not enabled [(EN1, EN2)  $\neq$  (HI, HI)] all internal timers and other circuit blocks are activated. The device then checks for short-circuits at the ISET and ILIM pins. If no short conditions exists, the device switches on the input FET Q1 with a 100mA current limit to checks for a short circuit at OUT. When  $V_{OUT}$  is above  $V_{SC}$ , the FET Q1 switches to the current limit threshold set by EN1, EN2 and  $R_{ILIM}$  and the device enters into the normal operation. During normal operation, the system is powered by the input source (Q1 is regulating), and the device continuously monitors the status of  $\overline{CE}$ , EN1 and EN2 as well as the input voltage conditions.



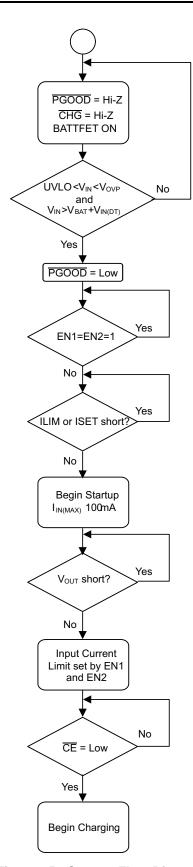


Figure 25. Startup Flow Diagram



## **OVERVOLTAGE PROTECTION (OVP)**

The bq24075-Q1 accepts inputs up to 28V without damage. Additionally, an overvoltage protection (OVP) circuit is implemented that shuts off the internal LDO and discontinues charging when  $V_{IN} > V_{OVP}$  for a period long than  $t_{DGL(OVP)}$ . When in OVP, the system output (OUT) is connected to the battery and PGOOD is high impedance. Once the OVP condition is removed, a new power on sequence starts (See the POWER ON section). The safety timers are reset and a new charge cycle will be indicated by the  $\overline{CHG}$  output.

### **DYNAMIC POWER-PATH MANAGEMENT**

The bq24075-Q1 features an OUT output that powers the external load connected to the battery. This output is active whenever a source is connected to IN or BAT. The following sections discuss the behavior of OUT with a source connected to IN to charge the battery and a battery source only.

### **INPUT SOURCE CONNECTED (ADAPTER or USB)**

With a source connected, the dynamic power-path management (DPPM) circuitry of the bq24075-Q1 monitors the input current continuously. The OUT output for the bq24075-Q1 is regulated to a fixed voltage ( $V_{O(REG)}$ ). The current into IN is shared between charging the battery and powering the system load at OUT. The bq24075-Q1 has internal selectable current limits of 100mA (USB100) and 500mA (USB500) for charging from USB ports, as well as a resistor-programmable input current limit.

The bq24075-Q1 is USB IF compliant for the inrush current testing. The USB spec allows up to  $10\mu$ F to be hard started, which establishes  $50\mu$ C as the maximum inrush charge value when exceeding 100mA. The input current limit for the bq24075-Q1 prevents the input current from exceeding this limit, even with system capacitances greater than  $10\mu$ F. Note that the input capacitance to the device must be selected small enough to prevent a violation (< $10\mu$ F), as this current is not limited. Figure 26 demonstrates the startup of the bq24075-Q1 and compares it to the USB-IF specification.

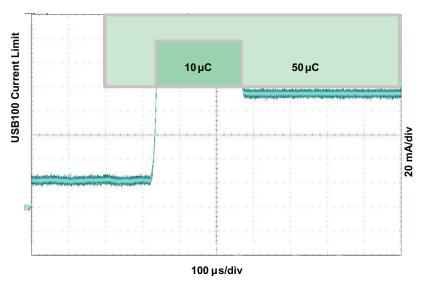


Figure 26. USB-IF Inrush Current Test

The input current limit selection is controlled by the state of the EN1 and EN2 pins as shown in Table 1. When using the resistor-programmable current limit, the input current limit is set by the value of the resistor connected from the ILIM pin to VSS, and is given by the equation:

$$I_{\text{IN-MAX}} = K_{\text{ILIM}}/R_{\text{ILIM}} \tag{1}$$

The input current limit is adjustable up to 1.5A. The valid resistor range is 1.1 k $\Omega$  to 8 k $\Omega$ .

When the IN source is connected, priority is given to the system load. The DPPM and Battery Supplement modes are used to maintain the system load. These modes are explained in detail in the following sections.



## Input DPM Mode (V<sub>IN</sub>-DPM)

The bq24075-Q1 uses the  $V_{IN}$ -DPM mode for operation from current-limited USB ports. When EN1 and EN2 are configured for USB100 (EN2=0, EN1=0) or USB500 (EN2=0, EN2=1) modes, the input voltage is monitored. If  $V_{IN}$  falls to  $V_{IN-DPM}$ , the input current limit is reduced to prevent the input voltage from falling further. This prevents the bq24075-Q1 from crashing poorly designed or incorrectly configured USB sources. Figure 27 shows the  $V_{IN-DPM}$  behavior to a current limited source. In this figure, the input source has a 400mA current limit and the device is in USB500 mode (EN1=1, EN2=0).

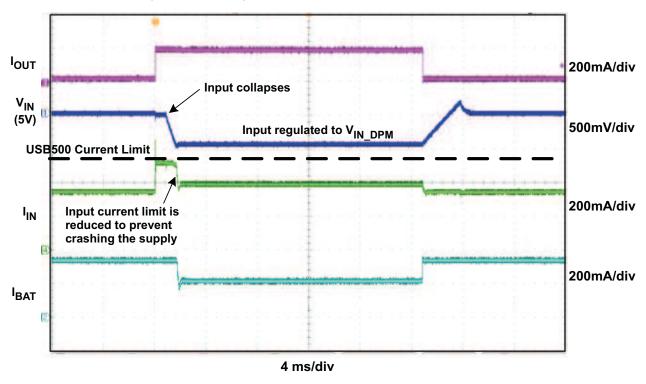


Figure 27. V<sub>IN</sub>-DPM Waveform

## **DPPM Mode**

When the sum of the charging and system load currents exceeds the maximum input current (programmed with EN1, EN2 and ILIM pins), the voltage at OUT decreases. Once the voltage on the OUT pin falls to  $V_{DPPM}$ , the bq24075-Q1 enters DPPM mode. In this mode, the charging current is reduced as the OUT current increases in order to maintain the system output. Battery termination is disabled while in DPPM mode.

#### **Battery Supplement Mode**

While in DPPM mode, if the charging current falls to zero and the system load current increases beyond the programmed input current limit, the voltage at OUT reduces further. When the OUT voltage drops below the  $V_{BSUP1}$  threshold, the battery supplements the system load. The battery stops supplementing the system load when the voltage at OUT rises above the  $V_{BSUP2}$  threshold.

During supplement mode, the battery supplement current is not regulated (BAT-FET is fully on), however there is a short circuit protection circuit built in. If during battery supplement mode, the voltage at OUT drops  $V_{O(SC2)}$  below the BAT voltage, the OUT output is turned off if the overload exists after  $t_{DGL(SC2)}$ . The short circuit recovery timer then starts counting. After  $t_{REC(SC2)}$ , OUT turns on and attempts to restart. If the short circuit remains, OUT is turned off and the counter restarts. Battery termination is disabled while in supplement mode.



#### INPUT SOURCE NOT CONNECTED

When no source is connected to the IN input, OUT is powered strictly from the battery. During this mode the current into OUT is not regulated, similar to *Battery Supplement Mode*, however the short circuit circuitry is active. If the OUT voltage falls below the BAT voltage by 250mV for longer than  $t_{DGL(SC2)}$ , OUT is turned off. The short circuit recovery timer then starts counting. After  $t_{REC(SC2)}$ , OUT turns on and attempts to restart. If the short circuit remains, OUT is turned off and the counter restarts. This ON/OFF cycle continues until the overload condition is removed.

#### **BATTERY CHARGING**

Set  $\overline{\text{CE}}$  low to initiate battery charging. First, the device checks for a short-circuit on the BAT pin by sourcing  $I_{\text{BAT}(SC)}$  to the battery and monitoring the voltage. When the BAT voltage exceeds  $V_{\text{BAT}(SC)}$ , the battery charging continues. The battery is charged in three phases: conditioning pre-charge, constant current fast charge (current regulation) and a constant voltage tapering (voltage regulation). In all charge phases, an internal control loop monitors the IC junction temperature and reduces the charge current if an internal temperature threshold is exceeded.

Figure 28 illustrates a normal Li-lon charge cycle using the bq24075-Q1:

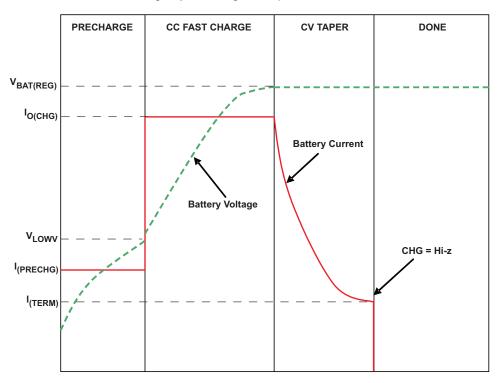


Figure 28. Typical Charge Cycle

In the pre-charge phase, the battery is charged at with the pre-charge current ( $I_{PRECHG}$ ). Once the battery voltage crosses the  $V_{LOWV}$  threshold, the battery is charged with the fast-charge current ( $I_{CHG}$ ). As the battery voltage reaches  $V_{BAT(REG)}$ , the battery is held at a constant voltage of  $V_{BAT(REG)}$  and the charge current tapers off as the battery approaches full charge. When the battery current reaches  $I_{TERM}$ , the  $\overline{CHG}$  pin indicates *charging done* by going high-impedance.

Note that termination detection is disabled whenever the charge rate is reduced because of the actions of the thermal loop, the DPPM loop or the  $V_{IN(LOW)}$  loop.

The value of the fast-charge current is set by the resistor connected from the ISET pin to VSS, and is given by the equation

 $I_{CHG} = K_{ISET}/R_{ISET}$ 



The charge current limit is adjustable up to 1.5A. The valid resistor range is  $590\Omega$  to 3 k $\Omega$ . Note that if  $I_{CHG}$  is programmed as greater than the input current limit, the battery will not charge at the rate of  $I_{CHG}$ , but at the slower rate of  $I_{IN(MAX)}$  (minus the load current on the OUT pin, if any). In this case, the charger timers will be proportionately slowed down.

#### CHARGE CURRENT TRANSLATOR

When the charger is enabled, internal circuits generate a current proportional to the charge current at the ISET input. The current out of ISET is 1/400 ( $\pm 10\%$ ) of the charge current. This current, when applied to the external charge current programming resistor,  $R_{\text{ISET}}$ , generates an analog voltage that can be monitored by an external host to calculate the current sourced from BAT.

$$V_{ISET} = I_{CHARGE} / 400 \times R_{ISET}$$
 (1)



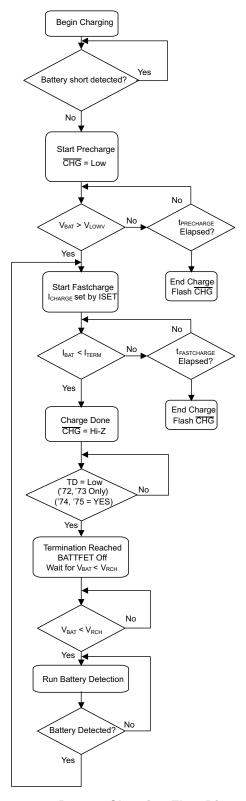


Figure 29. Battery Charging Flow Diagram



#### **BATTERY DETECTION AND RECHARGE**

The bq24075-Q1 automatically detects if a battery is connected or removed. Once a charge cycle is complete, the battery voltage is monitored. When the battery voltage falls below  $V_{RCH}$ , the battery detection routine is run. During battery detection, current ( $I_{BAT(DET)}$ ) is pulled from the battery for a duration  $t_{DET}$  to see if the voltage on BAT falls below  $V_{LOWV}$ . If not, charging begins. If it does, then it indicates that the battery is missing or the protector is open. Next, the precharge current is applied for  $t_{DET}$  to close the protector if possible. If  $V_{BAT} < V_{RCH}$ , then the protector closed and charging is initiated. If  $V_{BAT} > V_{RCH}$ , then the battery is determined to be missing and the detection routine continues.

# **BATTERY DISCONNECT (SYSOFF Input)**

The bq24075 feature a SYSOFF input that allows the user to turn the FET Q2 off and disconnect the battery from the OUT pin. This is useful for disconnecting the system load from the battery, factory programming where the battery is not installed or for host side impedance track fuel gauging, such as bq27500, where the battery open circuit voltage level must be detected before the battery charges or discharges. The /CHG output remains low when SYSOFF is high. Connect SYSOFF to VSS, to turn Q2 on for normal operation. SYSOFF is internally pulled to VBAT through  $\sim$ 5 M $\Omega$  resistor.

#### **DYNAMIC CHARGE TIMERS (TMR Input)**

The bq24075-Q1 device contains internal safety timers for the pre-charge and fast-charge phases to prevent potential damage to the battery and the system. The timers begin at the start of the respective charge cycles. The timer values are programmed by connecting a resistor from TMR to VSS. The resistor value is calculated using the following equation:

$$t_{PRECHG} = K_{TMR} \times R_{TMR}$$
  
 $t_{MAXCHG} = 10 \times K_{TMR} \times R_{TMR}$ 

Leave TMR unconnected to select the internal default timers. Disable the timers by connecting TMR to VSS.

Note that timers are suspended when the device is in thermal shutdown, and the timers are slowed proportionally to the charge current when the device enters thermal regulation.

During the fast charge phase, several events increase the timer durations.

- 1. The system load current activates the DPPM loop which reduces the available charging current
- 2. The input current is reduced because the input voltage has fallen to  $V_{IN(LOW)}$
- 3. The device has entered thermal regulation because the IC junction temperature has exceeded T<sub>J(REG)</sub>

During each of these events, the internal timers are slowed down proportionately to the reduction in charging current. For example, if the charging current is reduced by half for two minutes, the timer clock is reduced to half the frequency and the counter counts half as fast resulting in only one minute of "counting" time.

If the pre charge timer expires before the battery voltage reaches  $V_{LOWV}$ , the bq24075-Q1 indicates a fault condition. Additionally, if the battery current does not fall to  $I_{TERM}$  before the fast charge timer expires, a fault is indicated. The  $\overline{CHG}$  output flashes at approximately 2 Hz to indicate a fault condition. The fault condition is cleared by toggling  $\overline{CE}$  or the input power, entering/ exiting USB suspend mode, or an OVP event.

## STATUS INDICATORS (PGOOD, CHG)

The bq24075-Q1 contains two open-drain outputs that signal its status. The  $\overline{PGOOD}$  output signals when a valid input source is connected.  $\overline{PGOOD}$  is low when  $(V_{BAT} + V_{IN(DT)}) < V_{IN} < V_{OVP}$ . When the input voltage is outside of this range,  $\overline{PGOOD}$  is high impedance.

The charge cycle after power-up, CE going low, or exiting OVP is indicated with the  $\overline{\text{CHG}}$  pin on (low - LED on), whereas all refresh (subsequent) charges will result in the  $\overline{\text{CHG}}$  pin off (open - LED off). In addition, the  $\overline{\text{CHG}}$  signals timer faults by flashing at approximately 2 Hz.

Table 2. PGOOD STATUS INDICATOR

Input State	PGOOD Output
$V_{IN} < V_{UVLO}$	Hi impedance
$V_{UVLO} < V_{IN} < V_{IN(DT)}$	Hi impedance
$V_{IN(DT)} < V_{IN} < V_{OVP}$	Low



#### Table 2. PGOOD STATUS INDICATOR (continued)

Input State	PGOOD Output
$V_{IN} > V_{OVP}$	Hi impedance

### Table 3. CHG STATUS INDICATOR

Charge State	CHG Output
Charging	Low (for first shares evels)
Charging suspended by thermal loop	Low (for first charge cycle)
Safety timers expired	Flashing at 2Hz
Charging done	
Recharging after termination	III inno dano
IC disabled or no valid input power	Hi impedance
Battery absent	

#### THERMAL REGULATION AND THERMAL SHUTDOWN

The bq24075-Q1 contain a thermal regulation loop that monitors the die temperature. If the temperature exceeds  $T_{J(REG)}$ , the device automatically reduces the charging current to prevent the die temperature from increasing further. In some cases, the die temperature continues to rise despite the operation of the thermal loop, particularly under high VIN and heavy OUT system load conditions. Under these conditions, if the die temperature increases to  $T_{J(OFF)}$ , the input FET Q1 is turned OFF. FET Q2 is turned ON to ensure that the battery still powers the load on OUT. Once the device die temperature cools by  $T_{J(OFF-HYS)}$ , the input FET Q1 is turned on and the device returns to thermal regulation. Continuous overtemperature conditions result in a "hiccup" mode. During thermal regulation, the safety timers are slowed down proportionately to the reduction in current limit.

Note that this feature monitors the die temperature of the bq24075-Q1. This is not synonymous with ambient temperature. Self heating exists due to the power dissipated in the IC because of the linear nature of the battery charging algorithm and the LDO associated with OUT. A modified charge cycle with the thermal loop active is shown in Figure 30. Battery termination is disabled during thermal regulation.



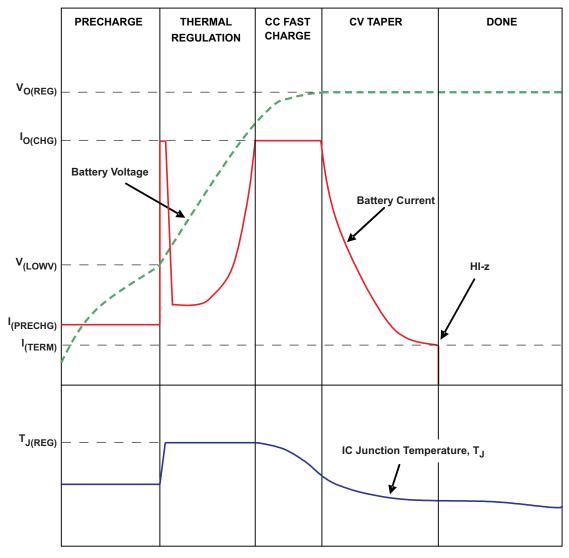


Figure 30. Charge Cycle Modified by Thermal Loop



#### BATTERY PACK TEMPERATURE MONITORING

The bq24075-Q1 features an external battery pack temperature monitoring input. The TS input connects to the NTC thermistor in the battery pack to monitor battery temperature and prevent dangerous over-temperature conditions. During charging,  $I_{NTC}$  is sourced to TS and the voltage at TS is continuously monitored. If, at any time, the voltage at TS is outside of the operating range ( $V_{COLD}$  to  $V_{HOT}$ ), charging is suspended. The timers maintain their values but suspend counting. When the voltage measured at TS returns to within the operation window, charging is resumed and the timers continue counting. When charging is suspended due to a battery pack temperature fault, the  $\overline{CHG}$  pin remains low and continues to indicate *charging*.

For applications that do not require the TS monitoring function, connect a  $10k\Omega$  resistor from TS to VSS to set the TS voltage at a valid level and maintain charging.

The allowed temperature range for 103AT-2 type thermistor is 0°C to 50°C. However, the user may increase the range by adding two external resistors. See Figure 31 for the circuit details. The values for Rs and Rp are calculated using the following equations:

$$Rs = \frac{-(R_{TH} + R_{TC}) \pm \sqrt{(R_{TH} + R_{TC})^2 - 4\left\{R_{TH} \times R_{TC} + \frac{V_H \times V_C}{(V_H - V_C) \times I_{TS}} \times (R_{TC} - R_{TH})\right\}}}{2}$$
(2)

$$Rp = \frac{V_{H} \times (R_{TH} + R_{S})}{I_{TS} \times (R_{TH} + R_{S}) - V_{H}}$$
(3)

Where:

R<sub>TH</sub>: Thermistor Hot Trip Value found in thermistor data sheet

R<sub>TC</sub>: Thermistor Cold Trip Value found in thermistor data sheet

V<sub>H</sub>: IC's Hot Trip Threshold = 0.3V nominal

V<sub>C</sub>: IC's Cold Trip Threshold = 2.1V nominal

I<sub>TS</sub>: IC's Output Current Bias = 75µA nominal

NTC Thermsitor Semitec 103AT-4

Rs and Rp 1% values were chosen closest to calculated values

Cold Temp Resistance and Trip Threshold; Ω (°C)	Hot Temp Resistance and Trip Threshold; Ω (°C)	External Bias Resistor, Rs (Ω)	External Bias Resistor, Rp (Ω)
28000 (-0.6)	4000 (51)	0	∞
28480 (-1)	3536 (55)	487	845000
28480 (-1)	3021 (60)	1000	549000
33890 (-5)	4026 (51)	76.8	158000
33890 (-5)	3536 (55)	576	150000
33890 (-5)	3021 (60)	1100	140000



RHOT and RCOLD are the thermistor resistance at the desired hot and cold temperatures, respectively. **Note** that the temperature window cannot be tightened more than using only the thermistor connected to TS, it can only be extended.

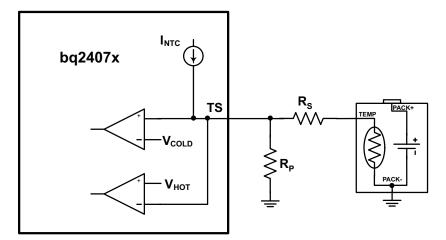


Figure 31. Extended TS Pin Thresholds



#### APPLICATIONS INFORMATION

### bq24075-Q1 CHARGER DESIGN EXAMPLE

See Figure 19 for Schematics of the Design Example.

### Requirements

- Supply voltage = 5V
- Fast charge current of approximately 800 mA; ISET pin 16
- Input Current Limit =1.3A; ILIM pin 12
- Termination Current Threshold = 110mA
- Safety timer duration, Fast-Charge = 6.25 hours; TMR pin 14
- TS Battery Temperature Sense =  $10k\Omega$  NTC (103AT-2)

### **Calculations**

## Program the Fast Charge Current (ISET):

 $R_{ISET} = K_{ISET} / I_{CHG}$ 

 $K_{ISFT}$  = 890 A $\Omega$  from the electrical characteristics table.

 $R_{ISFT} = 890A\Omega/0.8A = 1.1125 k\Omega$ 

Select the closest standard value, which for this case is 1.13kΩ. Connect this resistor between ISET (pin 16) and  $V_{SS}$ .

# Program the Input Current Limit (ILIM)

 $R_{ILIM} = K_{ILIM} / I_{I-MAX}$ 

 $K_{ILIM}$  = 1550 A $\Omega$  from the electrical characteristics table.

 $R_{ISET} = 1550A\Omega / 1.3A = 1.192 k\Omega$ 

Select the closest standard value, which for this case is 1.18 kΩ. Connect this resistor between ILIM (pin 12) and  $V_{SS}$ .

# Program 6.25-hour Fast-Charge Safety Timer (TMR)

 $R_{TMR} = t_{MAXCHG} / (10 \times K_{TMR})$ 

 $K_{TMR} = 48 \text{ s/k}\Omega$  from the electrical characteristics table.

 $R_{TMR} = (6.25 \text{ hr} \times 3600 \text{ s/hr}) / (10 \times 48 \text{ s/k}\Omega) = 46.8 \text{k}\Omega$ 

Select the closest standard value, which for this case is 46.4 kΩ. Connect this resistor between TMR (pin 2) and  $V_{SS}$ .

## **TS Function**

Use a  $10k\Omega$  NTC thermistor in the battery pack (103AT-2). For applications that do not require the TS monitoring function, connect a 10kΩ resistor from TS to VSS to set the TS voltage at a valid level and maintain charging.

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## **CHG** and **PGOOD**

LED Status: connect a  $1.5k\Omega$  resistor in series with a LED between OUT and  $\overline{CHG}$  to indicate charging status. Connect a  $1.5k\Omega$  resistor in series with a LED between OUT and  $\overline{PGOOD}$  to indicate when a valid input source is connected.

Processor Monitoring Status: connect a pullup resistor (on the order of 100 k $\Omega$ ) between the processor's power rail and  $\overline{CHG}$  and  $\overline{PGOOD}$ 

### System ON/OFF (SYSOFF)

Connect SYSOFF high to disconnect the battery from the system load. Connect SYSOFF low for normal operation

# **SELECTING IN, OUT AND BAT pin CAPACITORS**

In most applications, all that is needed is a high-frequency decoupling capacitor (ceramic) on the power pin, input, output and battery pins. Using the values shown on the application diagram, is recommended. After evaluation of these voltage signals with real system operational conditions, one can determine if capacitance values can be adjusted toward the minimum recommended values (DC load application) or higher values for fast high amplitude pulsed load applications. Note if designed high input voltage sources (bad adaptors or wrong adaptors), the capacitor needs to be rated appropriately. Ceramic capacitors are tested to 2x their rated values so a 16V capacitor may be adequate for a 30V transient (verify tested rating with capacitor manufacturer).

#### THERMAL PACKAGE

The bq24075 is packaged in a thermally enhanced MLP package. The package includes a thermal pad to provide an effective thermal contact between the IC and the printed circuit board (PCB). The power pad should be directly connected to the  $V_{SS}$  pin. Full PCB design guidelines for this package are provided in the application note entitled: QFN/SON PCB Attachment Application Note (SLUA271). The most common measure of package thermal performance is thermal impedance ( $\theta_{JA}$ ) measured (or modeled) from the chip junction to the air surrounding the package surface (ambient). The mathematical expression for  $\theta_{JA}$  is:

$$\theta_{JA} = (T_J - T) / P$$

Where:

 $T_J$  = chip junction temperature

T = ambient temperature

P = device power dissipation

Factors that can influence the measurement and calculation of  $\theta_{JA}$  include:

- 1. Whether or not the device is board mounted
- 2. Trace size, composition, thickness, and geometry
- 3. Orientation of the device (horizontal or vertical)
- 4. Volume of the ambient air surrounding the device under test and airflow
- 5. Whether other surfaces are in close proximity to the device being tested

Due to the charge profile of Li-Ion batteries the maximum power dissipation is typically seen at the beginning of the charge cycle when the battery voltage is at its lowest. Typically after fast charge begins the pack voltage increases to \$\pm\$3.4V within the first 2 minutes. The thermal time constant of the assembly typically takes a few minutes to heat up so when doing maximum power dissipation calculations, 3.4V is a good minimum voltage to use. This is verified, with the system and a fully discharged battery, by plotting temperature on the bottom of the PCB under the IC (pad should have multiple vias), the charge current and the battery voltage as a function of time. The fast charge current will start to taper off if the part goes into thermal regulation.



The device power dissipation, P, is a function of the charge rate and the voltage drop across the internal PowerFET. It can be calculated from the following equation when a battery pack is being charged:

$$P = [V_{(IN)} - V_{(OUT)}] \times I_{(OUT)} + [V_{(OUT)} - V_{(BAT)}] \times I_{(BAT)}$$
(3)

The thermal loop feature reduces the charge current to limit excessive IC junction temperature. It is recommended that the design not run in thermal regulation for typical operating conditions (nominal input voltage and nominal ambient temperatures) and use the feature for non typical situations such as hot environments or higher than normal input source voltage. With that said, the IC will still perform as described, if the thermal loop is always active.

# Half-Wave Adaptors

Some adapters implement a half rectifier topology, which causes the adapter output voltage to fall below the battery voltage during part of the cycle. To enable operation with adapters under those conditions, the bq24075-Q1 family keeps the charger on for at least 20 msec (typical) after the input power puts the part in sleep mode. This feature enables use of external adapters using 50 Hz networks. The input must not drop below the UVLO voltage for the charger to work properly. Thus, the battery voltage should be above the UVLO to help prevent the input from dropping out. Additional input capacitance may be needed.

# Sleep Mode

When the input is between UVLO and  $V_{IN(DT)}$ , the device enters sleep mode. After entering sleep mode for >20mS the internal FET connection between the IN and OUT pin is disabled and pulling the input to ground will not discharge the battery, other than the leakage on the BAT pin. If one has a full 1000mAHr battery and the leakage is  $10\mu$ A, then it would take 1000mAHr/ $10\mu$ A = 100000 hours (11.4 years) to discharge the battery. The battery's self discharge is typically 5 times higher than this.

### **Layout Tips**

- To obtain optimal performance, the decoupling capacitor from IN to GND (thermal pad) and the output filter capacitors from OUT to GND (thermal pad) should be placed as close as possible to the bq24075-Q1, with short trace runs to both IN, OUT and GND (thermal pad).
- All low-current GND connections should be kept separate from the high-current charge or discharge paths
  from the battery. Use a single-point ground technique incorporating both the small signal ground path and the
  power ground path.
- The high current charge paths into IN pin and from the OUT pin must be sized appropriately for the maximum charge current in order to avoid voltage drops in these traces
- The bq24075-Q1 family is packaged in a thermally enhanced MLP package. The package includes a thermal
  pad to provide an effective thermal contact between the IC and the printed circuit board (PCB); this thermal
  pad is also the main ground connection for the device. Connect the thermal pad to the PCB ground
  connection. Full PCB design guidelines for this package are provided in the application note entitled:
  QFN/SON PCB Attachment Application Note (SLUA271).



# **REVISION HISTORY**

Changes from Original (February 2012) to Revision A	Page
Changed the device status From: Product Preview To: Production	1
Changes from Revision A (March 2012) to Revision B	Page
Changed the Device HBM ESD and Device CDM ESD items in the Features List	1



10-Dec-2020

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
BQ24075QRGTRQ1	ACTIVE	VQFN	RGT	16	3000	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 125	SAM	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF BQ24075-Q1:



# **PACKAGE OPTION ADDENDUM**

10-Dec-2020

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

**PACKAGE MATERIALS INFORMATION** 

www.ti.com 11-Aug-2017

# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



## \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ24075QRGTRQ1	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
BQ24075QRGTRQ1	VQFN	RGT	16	3000	367.0	367.0	35.0	



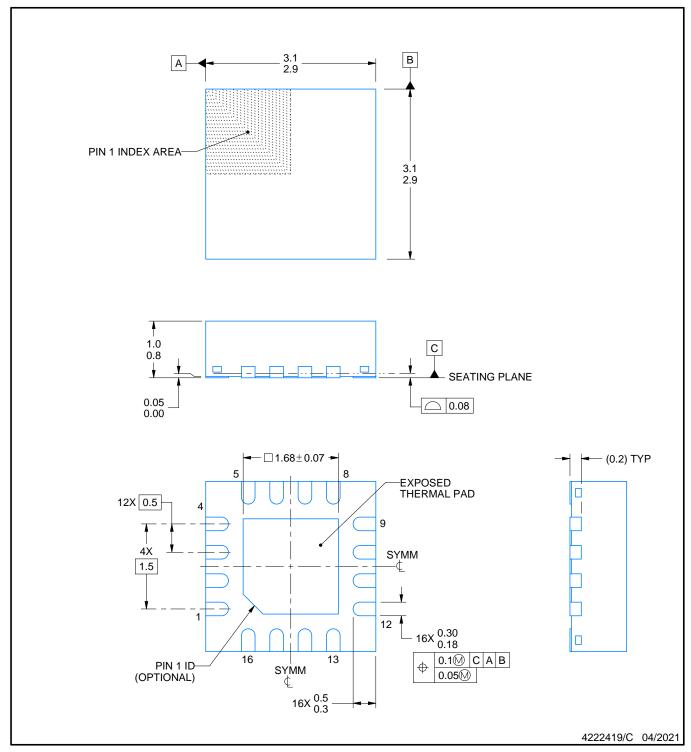
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.







PLASTIC QUAD FLATPACK - NO LEAD

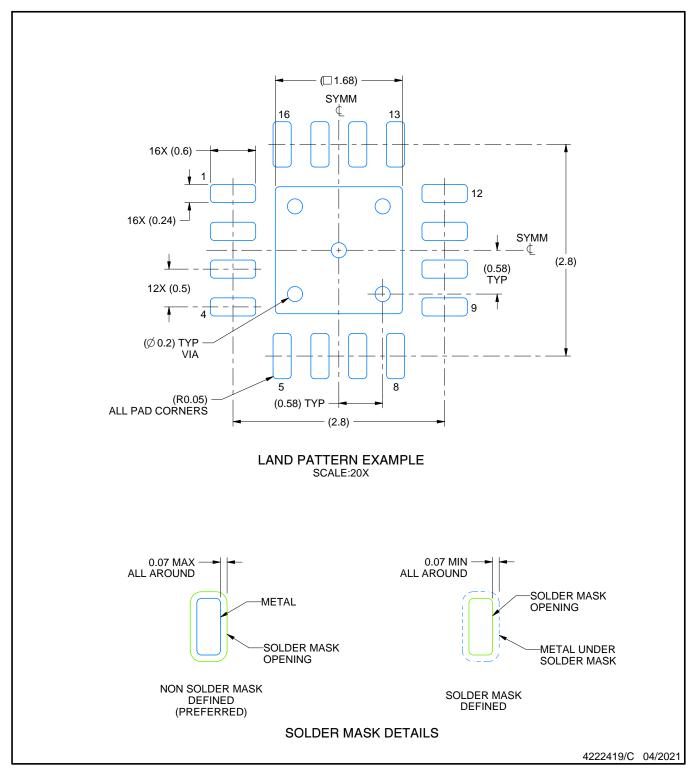


### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

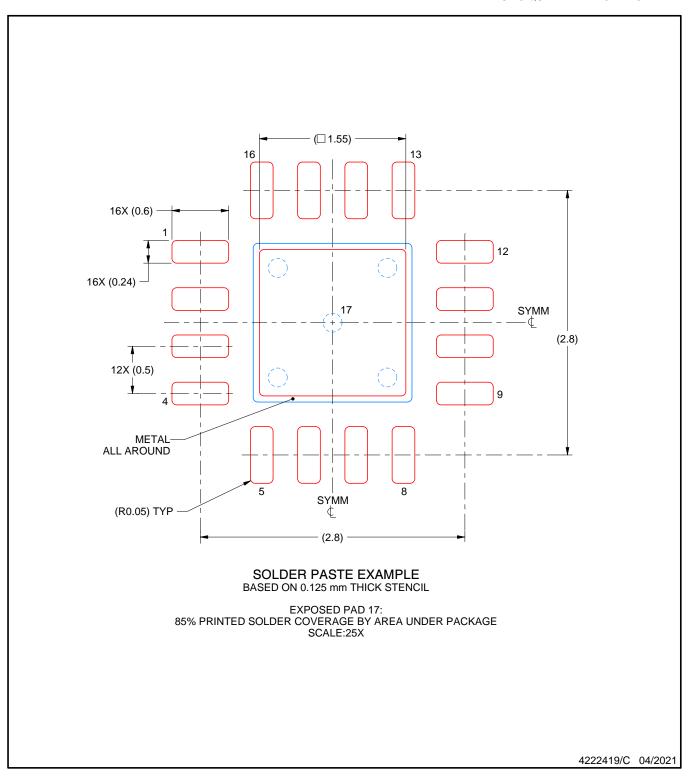


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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